BAV70 series

High-speed switching diodes Rev. 07 — 27 November 2007

Product data sheet

Product profile

1.1 General description

High-speed switching diodes, encapsulated in small Surface-Mounted Device (SMD) plastic packages.

Table 1. **Product overview**

Type number	Package			Package	Configuration
	NXP	JEITA	JEDEC	configuration	
BAV70	SOT23	-	TO-236AB	small	dual common cathode
BAV70M	SOT883	SC-101	-	leadless ultra small	dual common cathode
BAV70S	SOT363	SC-88	-	very small	quadruple common cathode
BAV70T	SOT416	SC-75	-	ultra small	dual common cathode
BAV70W	SOT323	SC-70	-	very small	dual common cathode

1.2 Features

- High switching speed: $t_{rr} \le 4$ ns
- Low leakage current
- Small SMD plastic packages
- Low capacitance: C_d ≤ 1.5 pF
- Reverse voltage: V_R ≤ 100 V

1.3 Applications

- High-speed switching
- General-purpose switching

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I _R	reverse current	$V_R = 80 V$	-	-	0.5	μΑ
V_R	reverse voltage		-	-	100	V
t _{rr}	reverse recovery time		<u>[1]</u> _	-	4	ns

^[1] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.



2. Pinning information

Table 3. **Pinning** Pin Description Simplified outline **Symbol** BAV70; BAV70T; BAV70W 1 anode (diode 1) 3 2 anode (diode 2) 3 common cathode 2 006aaa144 BAV70M anode (diode 1) 2 anode (diode 2) 3 common cathode Transparent top view BAV70S 1 anode (diode 1) 2 anode (diode 2) common cathode (diode 3 3 and diode 4) 4 anode (diode 3) 5 anode (diode 4) 006aab104 common cathode (diode 1 6

3. Ordering information

Table 4. Ordering information

and diode 2)

Type number	Package					
	Name	Description	Version			
BAV70	-	plastic surface-mounted package; 3 leads	SOT23			
BAV70M	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm	SOT883			
BAV70S	SC-88	plastic surface-mounted package; 6 leads	SOT363			
BAV70T	SC-75	plastic surface-mounted package; 3 leads	SOT416			
BAV70W	SC-70	plastic surface-mounted package; 3 leads	SOT323			

4. Marking

Table 5. Marking codes

<u> </u>	
Type number	Marking code ^[1]
BAV70	A4*
BAV70M	S4
BAV70S	A4*
BAV70T	A4
BAV70W	A4*

^{[1] * = -:} made in Hong Kong

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

			•		
Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V_{RRM}	repetitive peak reverse voltage		-	100	V
V_R	reverse voltage		-	100	V
I _F	forward current				
	BAV70	$T_{amb} \le 25 ^{\circ}C$	-	215	mA
	BAV70M	T _s = 90 °C	-	150	mA
	BAV70S	T _s = 60 °C	-	250	mA
	BAV70T	T _s = 90 °C	-	150	mA
	BAV70W	T _{amb} ≤ 25 °C	-	175	mA
I _{FRM}	repetitive peak forward current				
	BAV70		-	450	mA
	BAV70M		-	500	mA
	BAV70S		-	450	mA
	BAV70T		-	500	mA
	BAV70W		-	500	mA
I _{FSM}	non-repetitive peak forward	square wave	[1]		
	current	t _p = 1 μs	-	4	Α
		$t_p = 1 \text{ ms}$	-	1	Α
		t _p = 1 s	-	0.5	Α

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

High-speed switching diodes

Table 6. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
P _{tot}	total power dissipation		[2]		
	BAV70	$T_{amb} \le 25 ^{\circ}C$	-	250	mW
	BAV70M	$T_{amb} \le 25 ^{\circ}C$	[3] _	250	mW
	BAV70S	T _s = 60 °C	-	350	mW
	BAV70T	T _s = 90 °C	-	170	mW
	BAV70W	$T_{amb} \le 25 ^{\circ}C$	-	200	mW
Per device)				
l _F	forward current				
	BAV70	$T_{amb} \le 25 ^{\circ}C$	-	125	mA
	BAV70M	T _s = 90 °C	-	75	mA
	BAV70S	T _s = 60 °C	-	100	mA
	BAV70T	T _s = 90 °C	-	75	mA
	BAV70W	$T_{amb} \le 25 ^{\circ}C$	-	100	mA
T _j	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] $T_j = 25$ °C prior to surge.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u>			
	BAV70		-	-	500	K/W
	BAV70M		[2] _	-	500	K/W
	BAV70W		-	-	625	K/W
$R_{th(j-t)}$	thermal resistance from junction to tie-point					
	BAV70		-	-	360	K/W
	BAV70W		-	-	300	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point					
	BAV70S		-	-	255	K/W
	BAV70T		-	-	350	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[3] Reflow soldering is the only recommended soldering method.

^[2] Reflow soldering is the only recommended soldering method.

7. Characteristics

Table 8. Characteristics

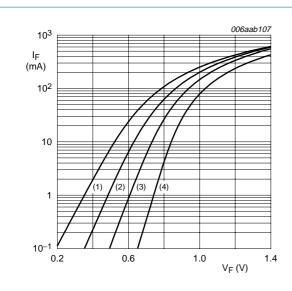
T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
V_{F}	forward voltage		[1]			
		$I_F = 1 \text{ mA}$	-	-	715	mV
		I _F = 10 mA	-	-	855	mV
		$I_F = 50 \text{ mA}$	-	-	1	V
		I _F = 150 mA	-	-	1.25	V
I _R	reverse current	V _R = 25 V	-	-	30	nΑ
		V _R = 80 V	-	-	0.5	μΑ
		V _R = 25 V; T _j = 150 °C	-	-	30	μΑ
		$V_R = 80 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	100	μΑ
C _d	diode capacitance	$V_R = 0 V$; $f = 1 MHz$	-	-	1.5	pF
t _{rr}	reverse recovery time		[2] _	-	4	ns
V_{FR}	forward recovery voltage		[3] _	-	1.75	V

^[1] Pulse test: $t_p \leq 300~\mu s;~\delta \leq 0.02.$

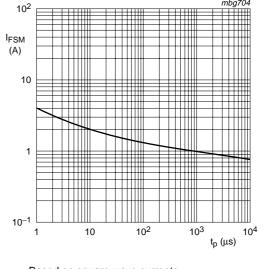
^[2] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 $\Omega;$ measured at I_R = 1 mA.

^[3] When switched from $I_F = 10$ mA; $t_r = 20$ ns.



- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \,^{\circ}C$
- (4) $T_{amb} = -40 \, ^{\circ}C$

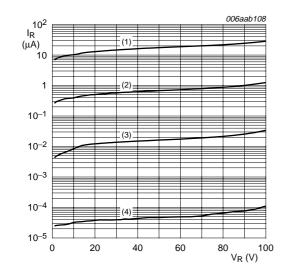
Fig 1. Forward current as a function of forward voltage; typical values



Based on square wave currents.

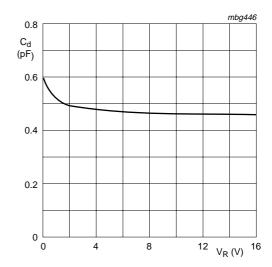
T_i = 25 °C; prior to surge

Fig 2. Non-repetitive peak forward current as a function of pulse duration; maximum values



- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 85 \,^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$
- (4) $T_{amb} = -40 \, ^{\circ}C$

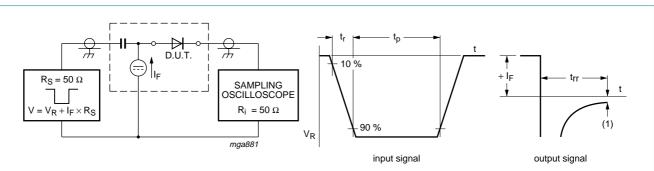
Fig 3. Reverse current as a function of reverse voltage; typical values



 $f = 1 \text{ MHz}; T_{amb} = 25 \, ^{\circ}\text{C}$

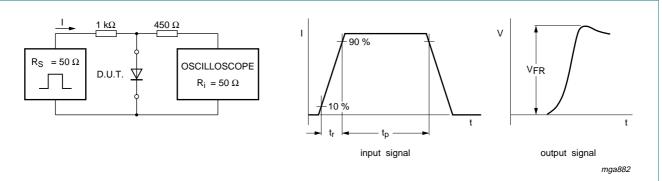
Fig 4. Diode capacitance as a function of reverse voltage; typical values

8. Test information



(1) $I_R = 1$ mA Input signal: reverse pulse rise time $t_r = 0.6$ ns; reverse voltage pulse duration $t_p = 100$ ns; duty cycle $\delta = 0.05$ Oscilloscope: rise time $t_r = 0.35$ ns

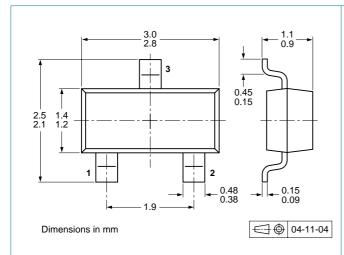
Fig 5. Reverse recovery time test circuit and waveforms



Input signal: forward pulse rise time t_r = 20 ns; forward current pulse duration $t_p \ge 100$ ns; duty cycle $\delta \le 0.005$

Fig 6. Forward recovery voltage test circuit and waveforms

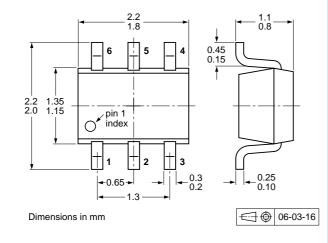
9. Package outline



0.62 0.55 0.55 0.47 0.30 0.22 0.30 0.22 0.30 0.22 2 0.12 0.30 0.22 0.30 0.30 0.22 0.30 0.3

Fig 7. Package outline BAV70 (SOT23/TO-236AB)

Fig 8. Package outline BAV70M (SOT883/SC-101)



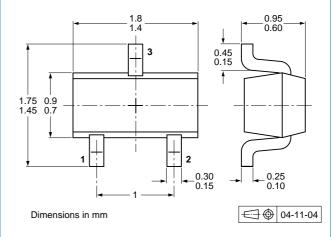


Fig 9. Package outline BAV70S (SOT363/SC-88)

Fig 10. Package outline BAV70T (SOT416/SC-75)

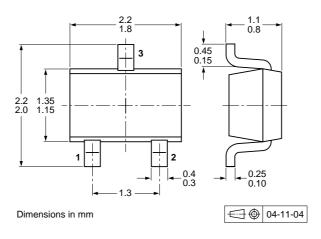


Fig 11. Package outline BAV70W (SOT323/SC-70)

10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

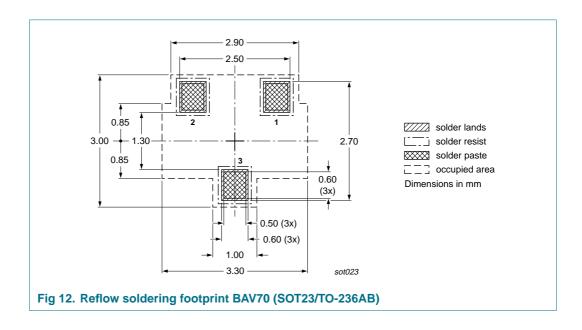
Type number	Package	Description			Packing quantity		
				3000	10000		
BAV70	SOT23	4 mm pitch, 8 mm tape and reel		-215	-235		
BAV70M	SOT883	2 mm pitch, 8 mm tape and reel		-	-315		
BAV70S	SOT363	4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-135		
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-165		
BAV70T	SOT416	4 mm pitch, 8 mm tape and reel		-115	-135		
BAV70W	SOT323	4 mm pitch, 8 mm tape and reel		-115	-135		

[1] For further information and the availability of packing methods, see Section 14.

[2] T1: normal taping

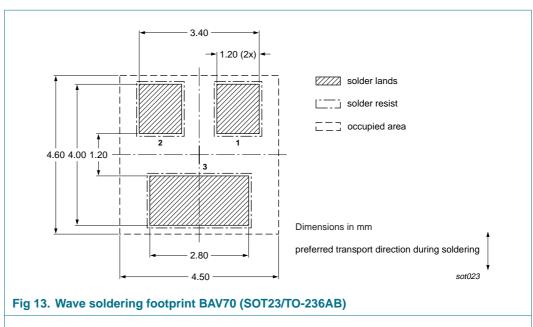
[3] T2: reverse taping

11. Soldering



BAV70 series

High-speed switching diodes



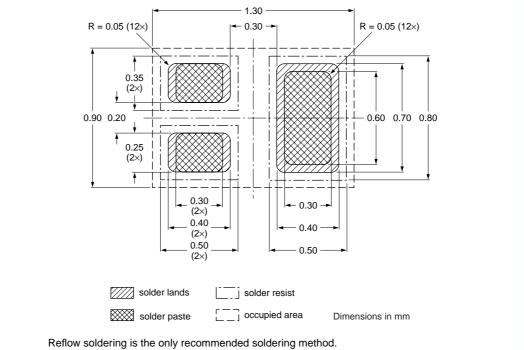
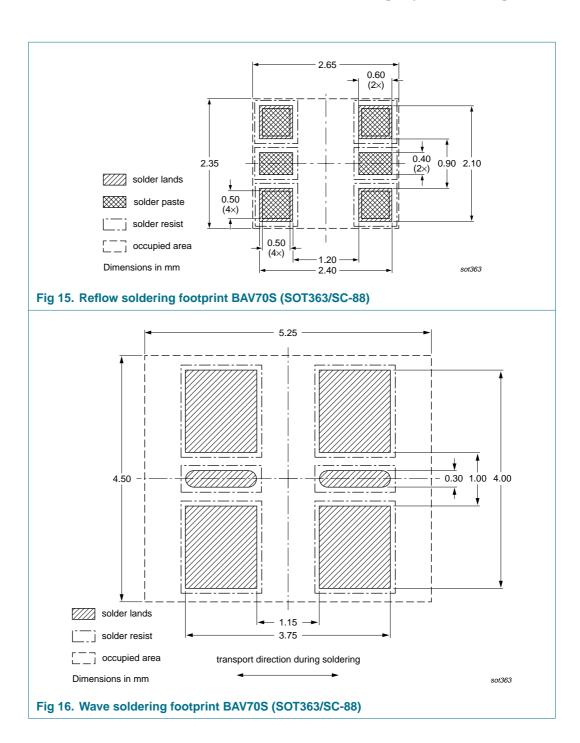
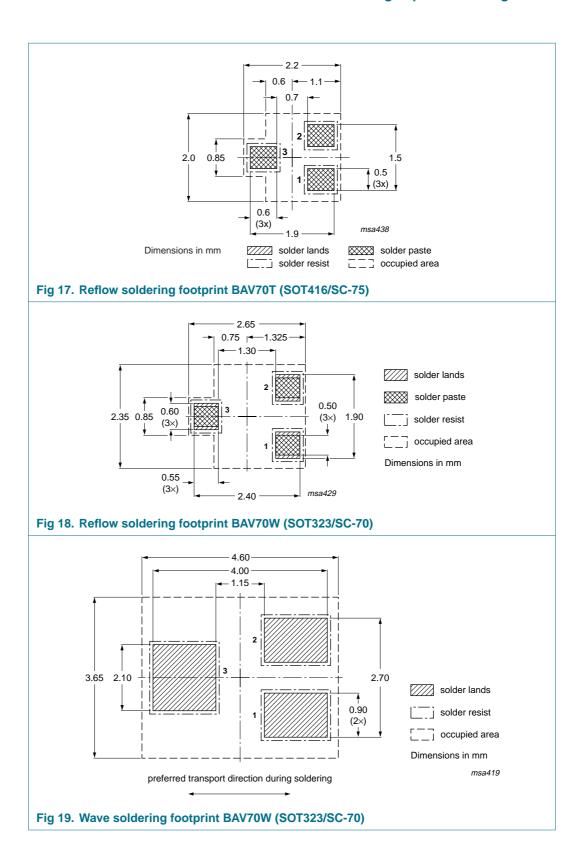


Fig 14. Reflow soldering footprint BAV70M (SOT883/SC-101)

High-speed switching diodes



High-speed switching diodes



12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAV70_SER_7	20071127	Product data sheet	-	BAV70_6 BAV70S_2 BAV70T_3 BAV70W_6
Modifications:	guidelines of Legal texts hat Type number Section 1.1 " Table 1 "Proce Table 2 "Quice Table 6 "Limit value from 88 Table 6 "Limit from 75 V to Table 8 "Chall IR condition V Table 8 "Chall from 2.5 μA to Table 8 "Chall from 2.5 μΑ to Table 8 "Chall from 3.5 μΑ to Table 8 "Cha	ting values": for BAV70, BA 100 V racteristics": for BAV70, BAV _R from 75 V to 80 V for T_j : racteristics": for BAV70, BA to 0.5 μ A for T_j = 25 °C racteristics": for BAV70T ch	ew company name when ided V70S and BAV70W chave and BAV70S and BAV70W chave and BAV70S, BAV70T and BAV70S, BAV70S, BAV70T and BAV70S, BAV70T and BAV70S,	re appropriate. ange of V_{RRM} maximum ange of V_R maximum value V70W change of ange of I_R maximum value alue from 2.0 μ A to 0.5 μ A V70W change of V; $T_j = 150 ^{\circ}$ C
BAV70_6	20020403	Product specification	-	BAV70_5
BAV70S_2	19971021	Product specification	-	BAV70S_1
BAV70T_3	20040204	Product specification	-	BAV70T_2
BAV70W_6	20020405	Product specification	-	BAV70W_5

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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BAV70 series

High-speed switching diodes

15. Contents

1	Product profile
1.1	General description
1.2	Features
1.3	Applications 1
1.4	Quick reference data
2	Pinning information 2
3	Ordering information
4	Marking 3
5	Limiting values 3
6	Thermal characteristics 4
7	Characteristics 5
8	Test information 7
9	Package outline 8
10	Packing information 9
11	Soldering 9
12	Revision history
13	Legal information 14
13.1	Data sheet status
13.2	Definitions
13.3	Disclaimers
13.4	Trademarks14
14	Contact information 14
15	Contents 15

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